

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOS III)

# SSM4K27CT

## ○ Switching Applications

- Small package
- Low on-resistance:  $R_{DS(ON)} = 205 \text{ m}\Omega \text{ (max) (@}V_{GS} = 4.0 \text{ V)}$   
 $R_{DS(ON)} = 260 \text{ m}\Omega \text{ (max) (@}V_{GS} = 2.5 \text{ V)}$   
 $R_{DS(ON)} = 390 \text{ m}\Omega \text{ (max) (@}V_{GS} = 1.8 \text{ V)}$

## Absolute Maximum Ratings (Ta = 25°C)

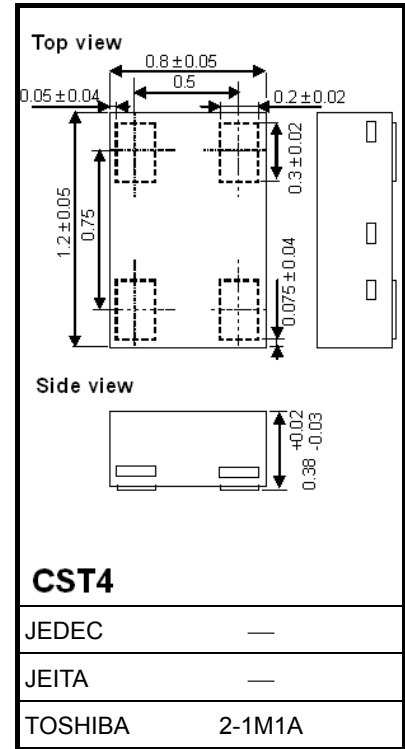
Characteristics	Symbol	Rating	Unit
Drain-Source voltage	$V_{DSS}$	20	V
Gate-Source voltage	$V_{GSS}$	$\pm 12$	V
Drain current	DC	$I_D$	0.5
	Pulse	$I_{DP}$	1.0
Power dissipation	$P_D$ (Note 1)	400	mW
Channel temperature	$T_{ch}$	150	°C
Storage temperature range	$T_{stg}$	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

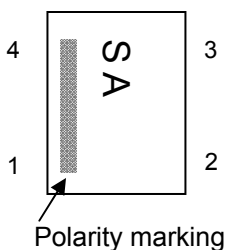
Note 1: Mounted on FR4 board.  
 (25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm<sup>2</sup>)

Unit: mm

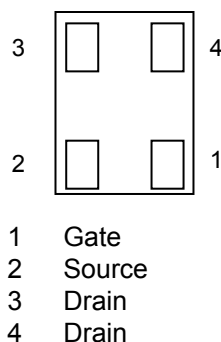


Weight: 1.1 mg (typ.)

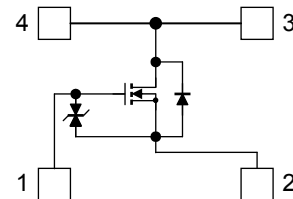
## Marking (top view)



## Electrode Layout (bottom view)



## Equivalent Circuit (top view)



## Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

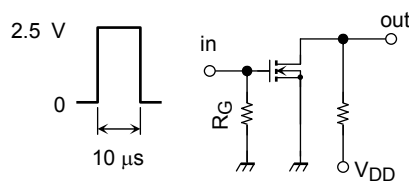
## Electrical Characteristics (Ta=25°C)

Characteristics	Symbol	Test Condition	Min.	Typ.	Max.	Unit	
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 12\text{ V}, V_{DS} = 0$	—	—	$\pm 1$	$\mu\text{A}$	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1\text{ mA}, V_{GS} = 0$	20	—	—	V	
	$V_{(BR)DSX}$	$I_D = 1\text{ mA}, V_{GS} = -12\text{ V}$	10	—	—		
Drain cut-off current	$I_{DSS}$	$V_{DS} = 20\text{ V}, V_{GS} = 0$	—	—	10	$\mu\text{A}$	
Gate threshold voltage	$V_{th}$	$V_{DS} = 3\text{ V}, I_D = 1\text{ mA}$	0.5	—	1.1	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 0.25\text{ A}$ (Note2)	0.8	1.6	—	S	
Drain-Source on-resistance	$R_{DS(ON)}$	$I_D = 0.25\text{ A}, V_{GS} = 4\text{ V}$ (Note2)	—	175	205	m $\Omega$	
		$I_D = 0.25\text{ A}, V_{GS} = 2.5\text{ V}$ (Note2)	—	200	260		
		$I_D = 0.10\text{ A}, V_{GS} = 1.8\text{ V}$ (Note2)	—	250	390		
Input capacitance	$C_{iss}$	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	174	—	pF	
Reverse transfer capacitance	$C_{riss}$	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	25	—	pF	
Output capacitance	$C_{oss}$	$V_{DS} = 10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	31	—	pF	
Switching time	Turn-on time	$t_{on}$	$V_{DD} = 10\text{ V}, I_D = 0.25\text{ A},$		—	10	ns
	Turn-off time	$t_{off}$	$V_{GS} = 0 \sim 2.5\text{ V}, R_G = 4.7\ \Omega$		—	12	

Note2: Pulse test

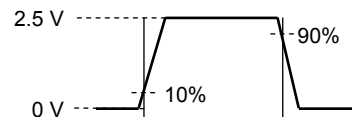
## Switching Time Test Circuit

### (a) Test Circuit

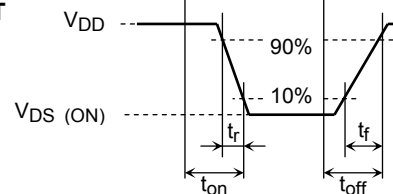


$V_{DD} = 10\text{ V}$   
 $R_G = 4.7\ \Omega$   
 Duty  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5\text{ ns}$   
 Common Source  
 $T_a = 25^\circ\text{C}$

### (b) $V_{IN}$



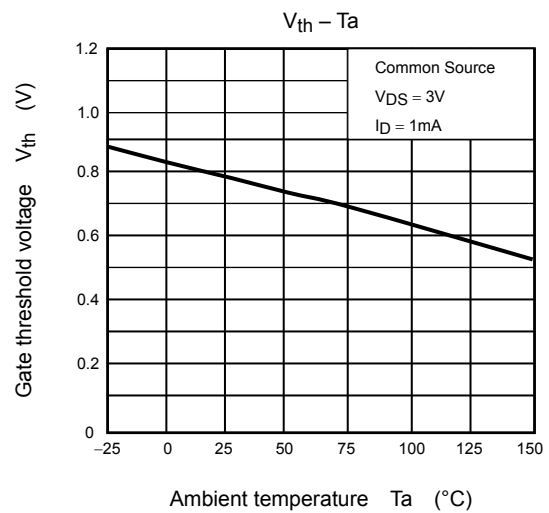
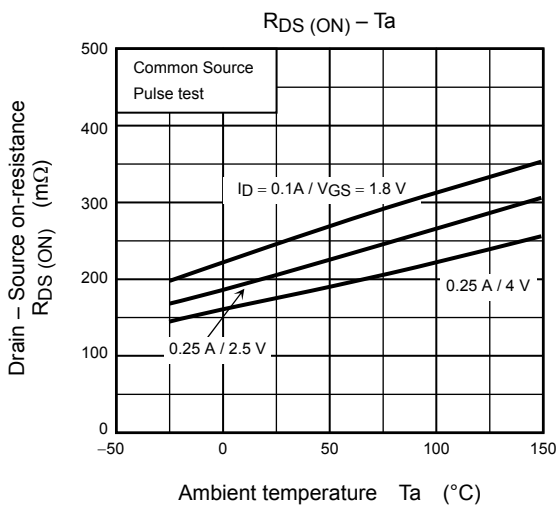
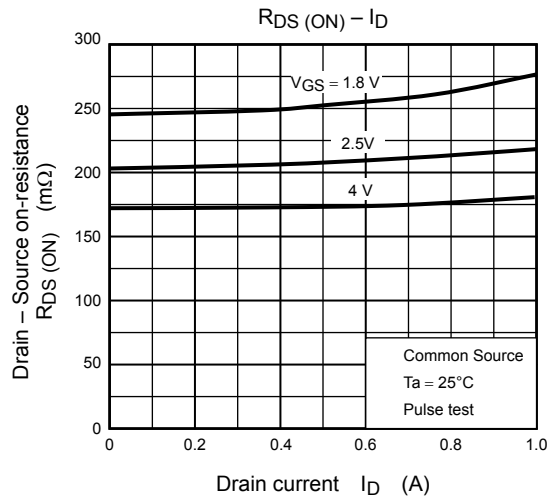
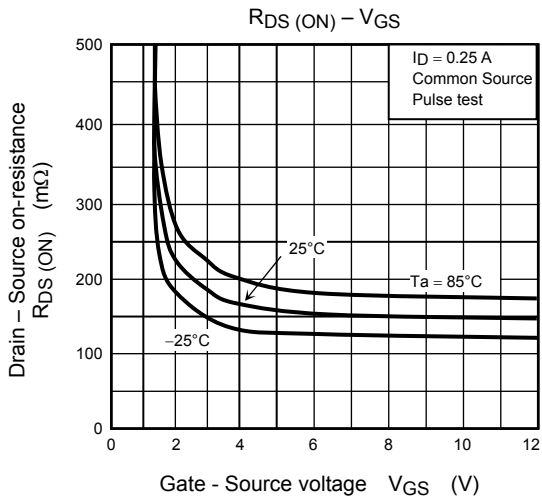
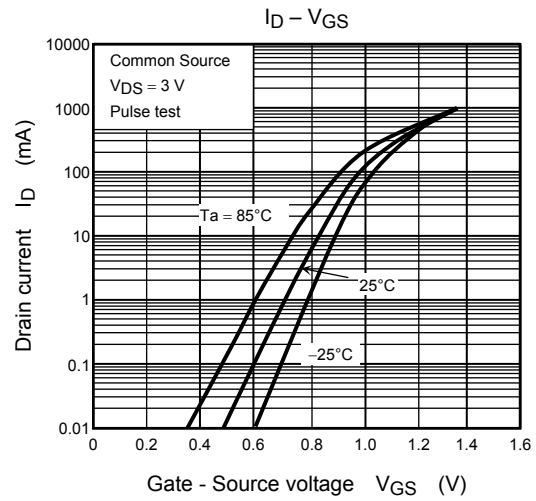
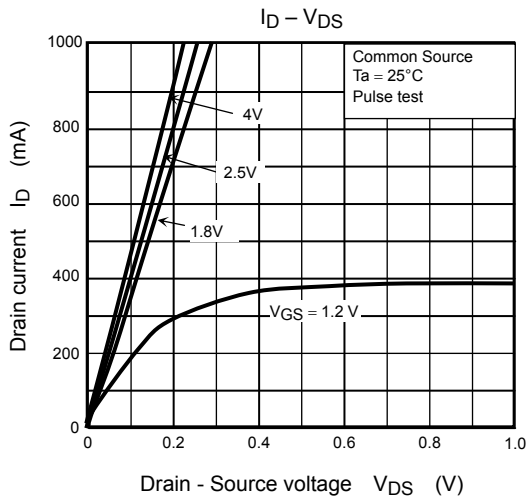
### (c) $V_{OUT}$

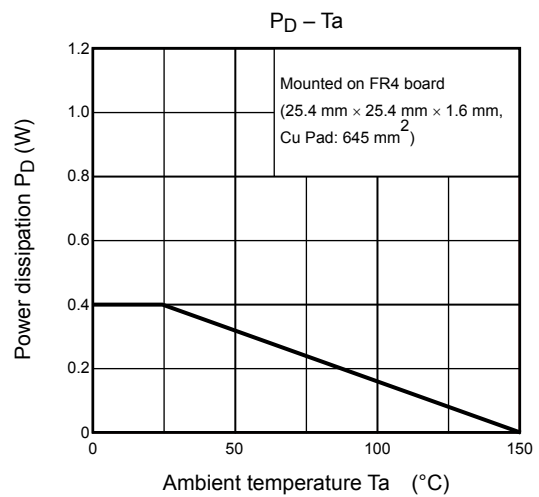
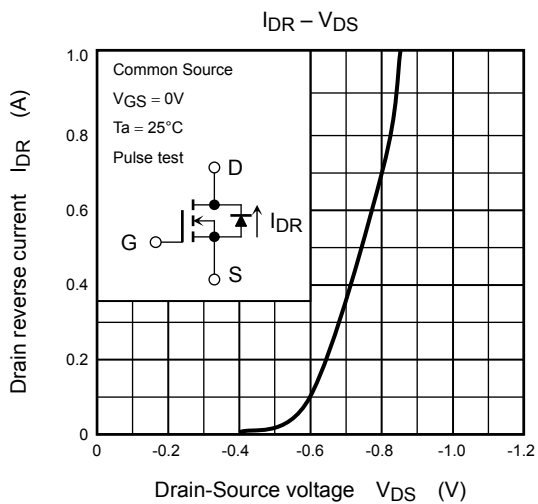
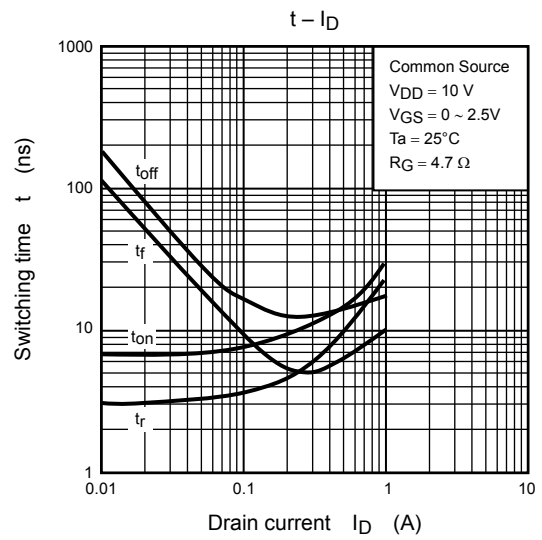
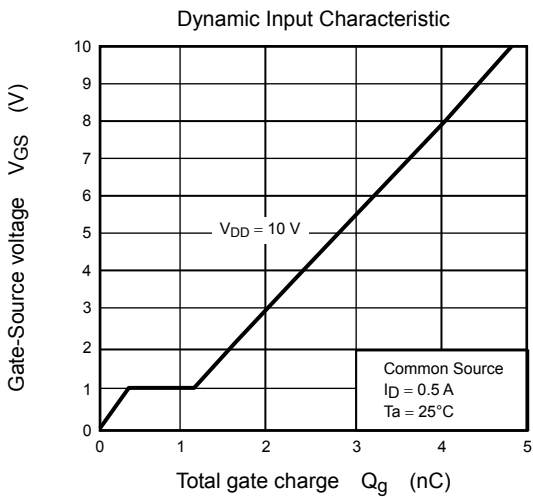
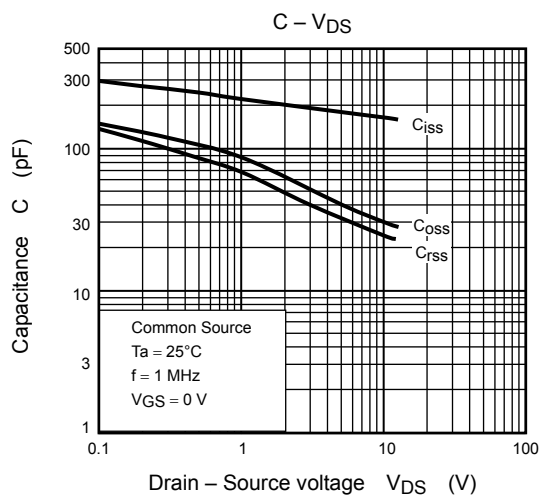
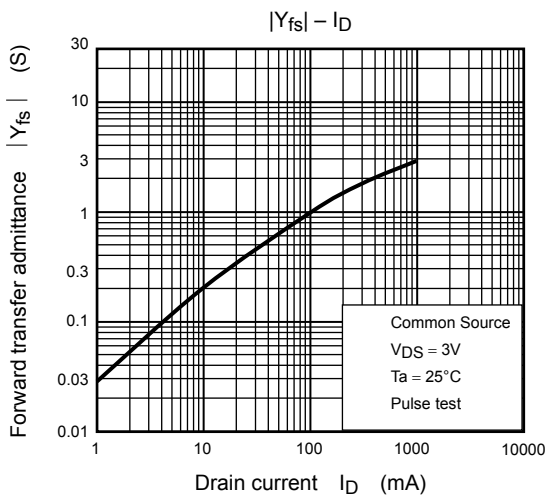


## Precaution

$V_{th}$  can be expressed as the voltage between the gate and source when the low operating current value is  $I_D = 1\text{ mA}$  for this product. For normal switching operation,  $V_{GS(ON)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(OFF)}$  requires a lower voltage than  $V_{th}$ . (The relationship can be established as follows:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .)

Be sure to take this into consideration when using the device.





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